

HL40023MG - 405nm band / 500mW -

GaN Violet High Power Laser Diode

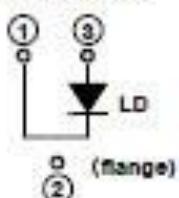
Preliminary
Rev.2
24. Nov. 2010

■ Applications

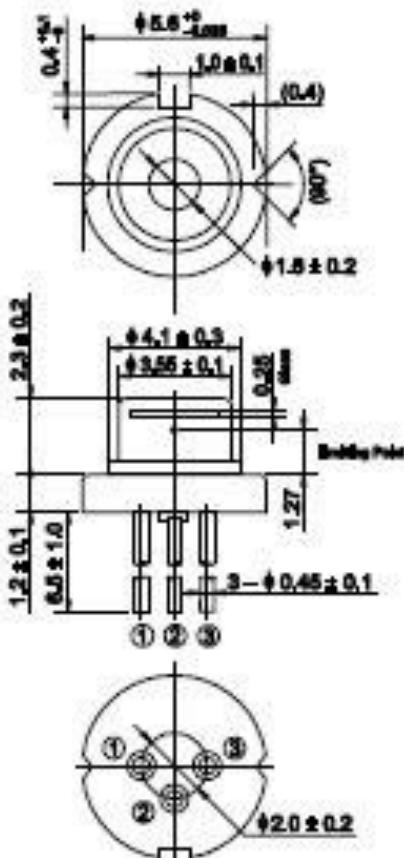
- Direct Imaging for PCB
- Industry

■ Internal circuit

• HL40023MG



■ Outline



■ Features

- Optical output power: Po=400mW(CW)
- Violet lasing : $\lambda_p=398\text{--}410\text{nm}$
- Low operating current: Iop=390mA Typ.
- Low operating voltage: Vop=5.5V Max.
- Small package: $\phi 5.6\text{mm}$
- Multi transverse mode oscillation

■ Absolute Maximum Ratings($T_c=25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Optical output power	Po	500	mW
LD Reverse Voltage	V _{RLD}	2	V
Operating Temperature	T _{opr}	0 ~ +30	°C
Storage Temperature	T _{stg}	-40 ~ +85	°C

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■ Optical and Electrical Characteristics($T_c=25^\circ\text{C}$)

Item	Symbol	Min.	Typ.	Max.	Unit	Test condition
Threshold current	I _{th}	-	-	160	mA	-
Operating current	I _{op}	-	390	420	mA	Po=400mW
Operating voltage	V _{op}	-	-	5.5	V	Po=400mW
Lasing Wavelength	λ_p	398	-	410	nm	Po=400mW
Beam divergence Parallel to the junction	θ_{\parallel}	5	-	25	°	Po=400mW, Full angle 1/e ²
Beam divergence Perpendicular to the junction	θ_{\perp}	30	-	60	°	Po=400mW, Full angle 1/e ²